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Jacqueline J Garner

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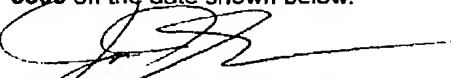
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 10/023,825 Confirmation No. 8239
Applicant : Jorge A. Kittl et al.
Filed : 12/19/2001
TC/A.U. : 2829
Examiner : Russell M. Kobert
Docket No. : TI-23892
Customer No. : 23494
Title : METHOD TO IMPROVE SILICIDE FORMATION ON
POLYSILICON

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January 20, 2004
Date

FACSIMILE COVER SHEET

<input checked="" type="checkbox"/> FACSIMILE COVER SHEET	<input checked="" type="checkbox"/> AMENDMENT (6 Pages)
<input type="checkbox"/> NEW APPLICATION	<input checked="" type="checkbox"/> EOT 1mth (3 Pages)
<input type="checkbox"/> DECLARATION (# Pages)	<input type="checkbox"/> NOTICE OF APPEAL (# Pages)
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<input type="checkbox"/> CONTINUATION APP'N (# Pages)	
<input type="checkbox"/> DIVISIONAL APP'N	
NAME OF INVENTOR(S):	
Kittl	
TITLE OF INVENTION:	
Method to Improve Silicide Formation . . .	
TI FILE NO.:	DEPOSIT ACCT. NO.:
TI-23892	20-0668
FAXED: 1/20/2004	
DUE: 12/17/2003	
ATTY/SECY: JJG	
RECEIPT DATE & SERIAL NO.:	
Serial No.: 10/023,825	
Filing Date: 12/19/2001	
Conf. No. 8239	

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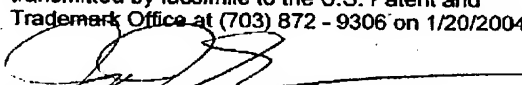
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Jacqueline J. Garner
Reg. No. 36,144

The following amendments and remarks are offered in response to the Examiner's Office Action dated 9/17/2003. They are respectfully submitted as a full and complete response to that Action.

Please amend the above-referenced application as follows:

Amendments to the ABSTRACT begin on page 2.

Amendments to the Claims are reflected in the listing of claims that begin on page 3 of this paper.

There are no **Amendments to the Drawings**.

The **Remarks** begin on page 4.